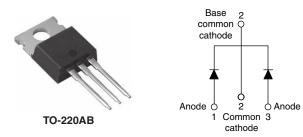


Vishay Semiconductors

Schottky Rectifier, 2 x 30 A



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 30 A				
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.57 V				
I _{RM} max.	40 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	27 mJ				

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



RoHS COMPLIANT HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform (per device)	60	A				
V _{RRM}		35 to 45	V				
I _{FRM}	T _C = 142 °C (per leg)	60	A				
I _{FSM}	t _p = 5 μs sine	2600					
V _F	30 A _{pk} , T _J = 125 °C	0.57	V				
TJ	Range	- 65 to 175	°C				

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS- 61CTQ035PbF	VS- 61CTQ035-N3	VS- 61CTQ040PbF	VS- 61CTQ040-N3	VS- 61CTQ045PbF	VS- 61CTQ045-N3	UNITS	
Maximum DC reverse voltage	V _R								
Maximum working peak reverse voltage	V _{RWM}	35	35	40	40	45	45	V	

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average per le		$T_{\rm C}$ = 142 °C, rated V _B		30				
forward current per devic	e I _{F(AV)}	$T_{\rm C} = 142$ C, fated $V_{\rm R}$	60	А				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 142 $^{\circ}$ C			60			
Maximum peak one cycle non-repetitive	150.4	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2600				
surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	350				
Non-repetitive avalanche energy per leg		T _J = 25 °C, I _{AS} = 4 A, L = 3.4 mH		27	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		4	А			

Revision: 29-Aug-11

Document Number: 94241

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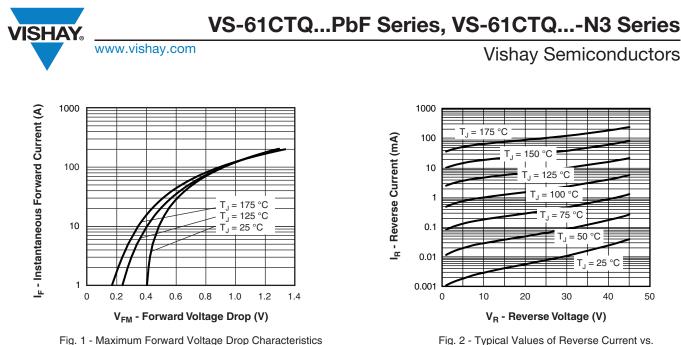
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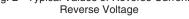
ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
		30 A	T.I = 25 °C	0.57	0.61				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	1] = 25 0	0.72	0.76	V			
	VFM (1)	30 A	T 105 00	0.53	0.57				
		60 A	T _J = 125 °C	0.70	0.74				
Maximum instantaneous reverse current	I _{RM}	$T_J = 25 \ ^\circ C$	Rated DC voltage	0.06	1	mA			
waximum instantaneous reverse current		T _J = 125 °C	Haled DC Vollage	21	40	mA			
Maximum junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C			00	pF			
Typical series inductance	L _S	Measured from top of terminal to mounting plane			.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R 10 000							

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

THERMAL - MECHANICAL S	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65 to 175	°C					
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	R _{thCS} Mounting surface, smooth and greased		0/11					
Approximate weight			2	g					
			0.07	oz.					
Mounting torque	n	Non-lubricated threads	6 (5)	kgf ⋅ cm					
Mounting torque maximur	n	Non-lubricated threads		(lbf ⋅ in)					
			61CTQ035						
Marking device		Case style TO-220AB	61CTQ040						
			61CTQ045						





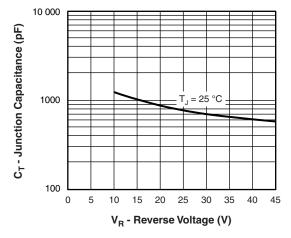
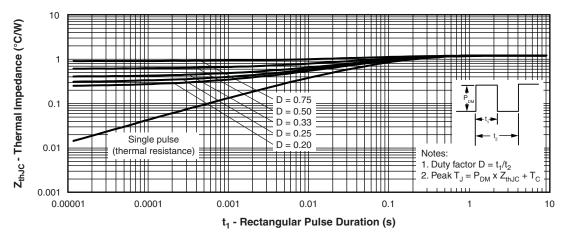
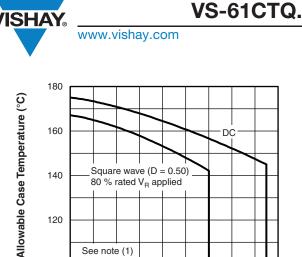


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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120

100

0 5 10 15 20 25 30 35 40 45

See note (1)

VS-61CTQ...PbF Series, VS-61CTQ...-N3 Series

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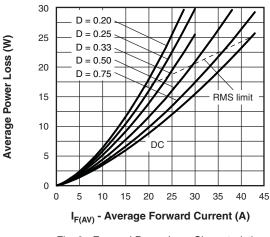


Fig. 6 - Forward Power Loss Characteristics



I_{F(AV)} - Average Forward Current (A)

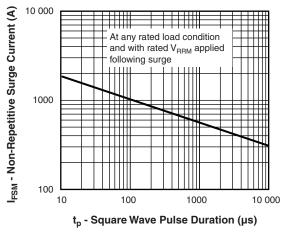


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	61	С	т	Q	045	PbF
	1	2	3	4	5	6	7
1	-	Vishay	Semico	nductor	s produ	ct	
2	-	Curren	t rating ((60 = 60	A)		
3	-	Circuit	Circuit configuration				
		C = Co	mmon d	athode			
4	-	Packag	je				
		T = TO	-220				
5	-	Schott	ky "Q" se	eries			035 = 35
6	-	Voltage	e ratings	s ———			040 = 40
7	-	Environmental digit 045 =				045 = 45	
		• PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-61CTQ035PbF	50	1000	Antistatic plastic tube				
VS-61CTQ035-N3	50	1000	Antistatic plastic tube				
VS-61CTQ040PbF	50	1000	Antistatic plastic tube				
VS-61CTQ040-N3	50	1000	Antistatic plastic tube				
VS-61CTQ045PbF	50	1000	Antistatic plastic tube				
VS-61CTQ045-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			

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3 x b

3 x b2

Detail B

(b, b2)

b1. b3 Section C - C and D - D

L1 (2)

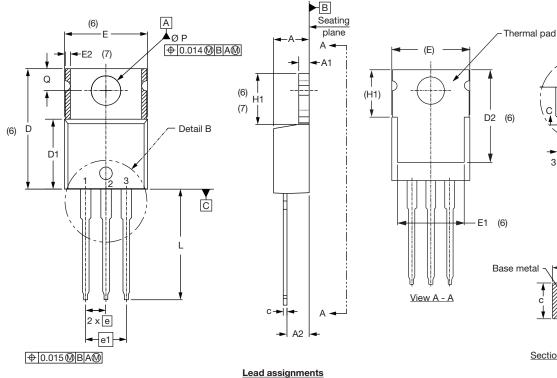
- Plating

c1 (4)

(4)

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

- **Diodes**
- 1. Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

(7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

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